



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: E. I. Broekaart
SERIAL NO.: 09/804,004 EXAMINER: Nathan W. Ha
FILED: March 12, 2001 ART UNIT: 2814
FOR: A METHOD OF MANUFACTURING A SEMICONDUCTOR
DEVICE

2814
12/B
G. S. Study
3-6-03

Assistant Commissioner for Patents
Washington, DC 20231

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TECHNOLOGY CENTER 2800

AMENDMENT

Dear Sir:

In response to the Office Action dated November 25, 2002, please amend the
application as follows:

IN THE CLAIMS:

Amend claim 1 as follows:

1. (Amended) A method of manufacturing an electronic device, a
semiconductor device in particular but not exclusively, which method comprises the steps
of:

applying a semiconductor substrate (1) which is provided with a conductor (3,4,5)
at a surface (2), the conductor (3,4,5) having a top surface portion (6) and sidewall
portions (7), of which at least the top surface portion (6) is provided with an etch stop
layer (12) comprising silicon carbide;

applying a dielectric layer (13);

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